Roll No.

Total Pages: 03

BT-3/D-19

33083

DIGITAL ELECTRONICS CSE-207N

Time: Three Hours]

[Maximum Marks: 75

Note: Attempt Five questions in all, selecting one question from each Unit. Q. No. 1 is compulsory. All questions carry equal marks.

- Differentiate between Minterm and Maxterm. (a) 3
 - (b) Discuss fast adder design procedure.
 - Differentiate between D-type and T-type flip-flop.

Explain EAROM.



Unit I

Explain Quine Mc-Clusky (QM) method of minimization? Simplify the following expression using QM method, also verify the results by K map method :

 $F = \Sigma A$, B, C, D $m(1, 3, 7, 11, 15) + \Sigma d(0, 2, 5) 15$

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Realize the following logic equation using only (a) 3. NOR gates:

$$(A + B).(C + D) = (A + B) + (C + D)$$
 5

- 5 Explain principle of duality. (b)
- Tristate outputs. (c)

Unit II

- Describe encoder using logic circuit. Explain (a) encoder with decoder can be used as coder converter.
 - 10

5

6

- 5 Explain magnitude comparator. (b)
- Design a 40: 1 multiplexer using 8: 1 multiplexers. 5. (a)
 - Write brief note on adder with look ahead carry. 5 (b)
 - Design a BCD to Gray code convertor using NAND (c) gates only.

Unit III

- What is the difference between race around condition (a) and undefined state? Explain, how the race around 9 condition is removed in J-K flip-flop?
 - Draw and discuss master slave flip-flop.

7.	Write short notes on the following:		
	(a)	Sequence generator	
	(b)	Modulo-n counter	
	(c)	Universal shift registers.	15
		Unit IV	
8.	Explain the following in brief:		
	(a)	MOSFET RAM cell structure	
	(b)	Bipolar RAM cell	
	(c)	Differentiate between PLA and PAL.	15
9.	Write short notes on the following:		
	(a)	Memory expansion	
	(b)	PROM	



15

(c) FPGA.